



Istituto Nazionale di Fisica Nucleare

16th Topical Seminar on Innovative Particle and Radiation Detectors

Design validation of the CMS Phase-2 Triple-GEM Detectors

Federica M. Simone^{1,2}, Antonello Pellecchia², Piet Verwilligen²
on behalf of the CMS Muon group

¹Bari Physics Department, ²INFN Bari

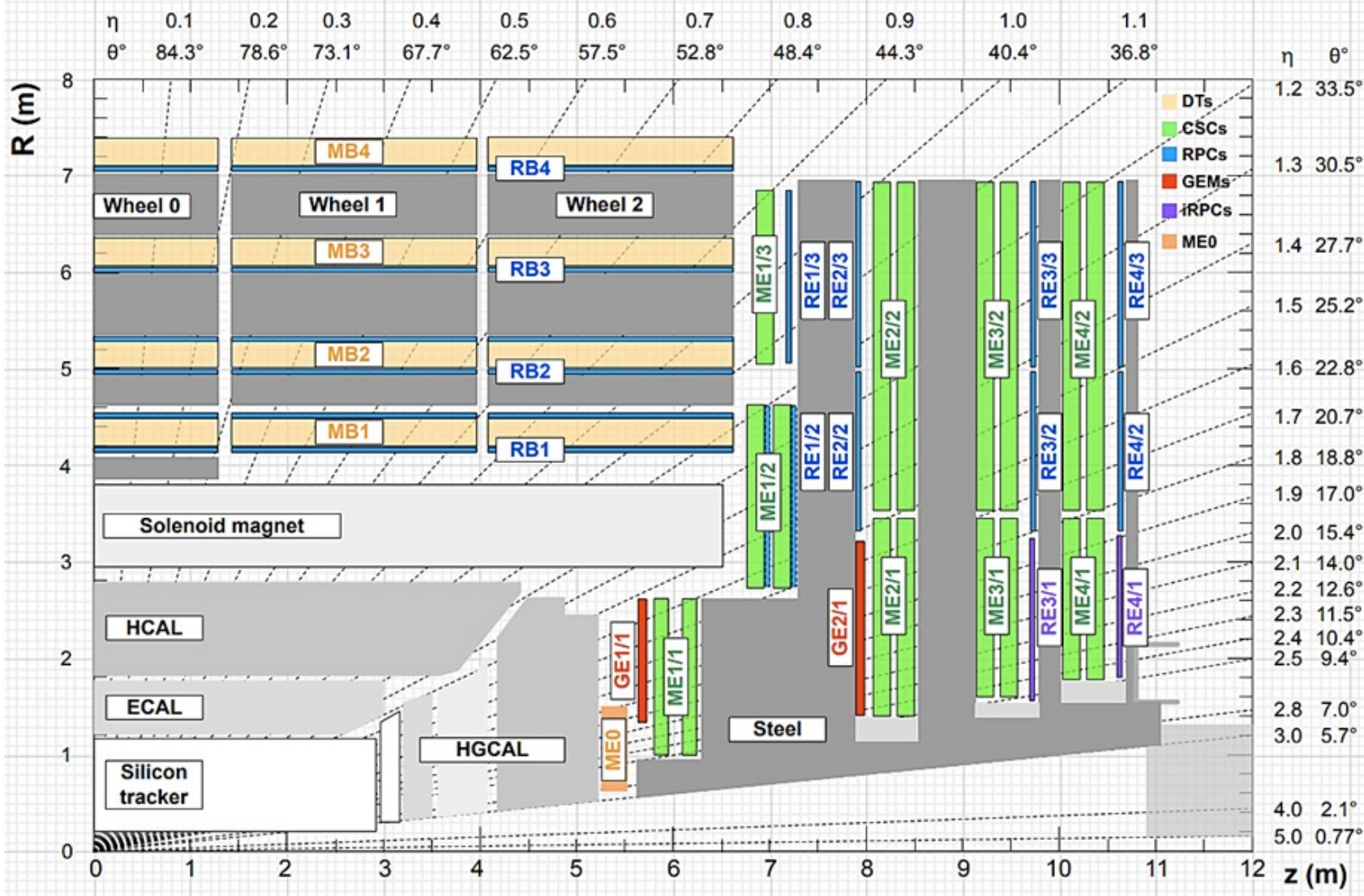
25-29 September 2023, Siena, Italy

Outline

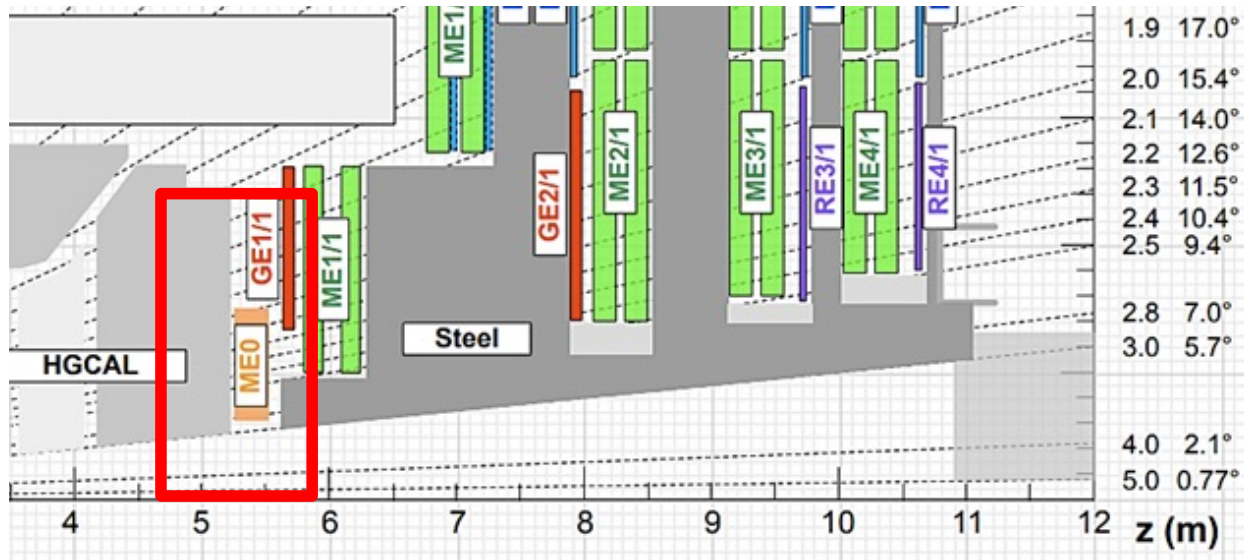
- The GEM Phase-2 upgrade
- ME0 background
- ME0 detector design
- Rate capability studies
 - Validation of the foil design
 - Studies on the full RO chain



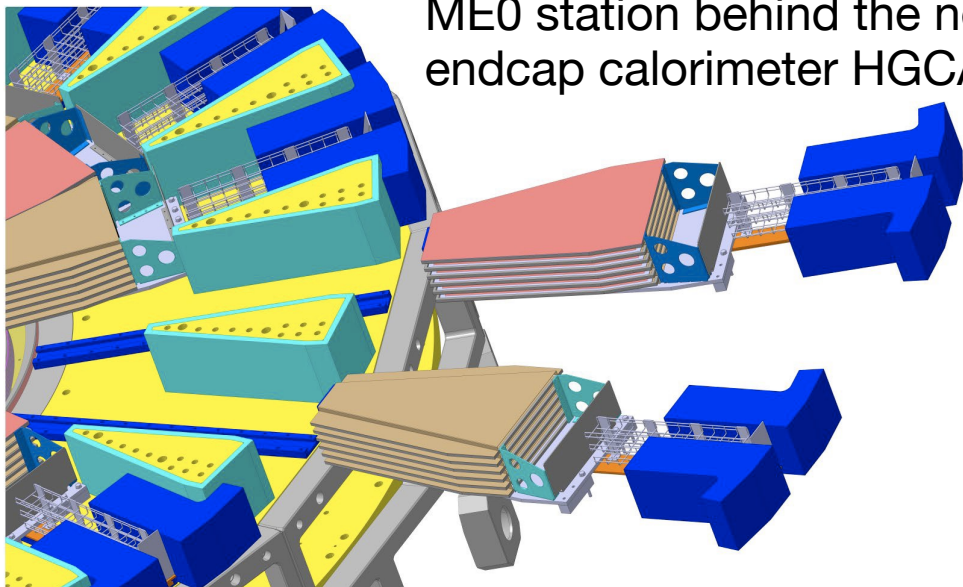
The Muon System Phase-2 Upgrade



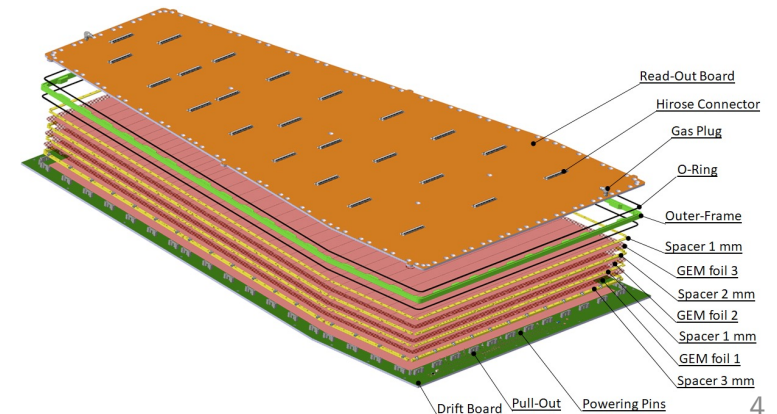
The ME0 upgrade



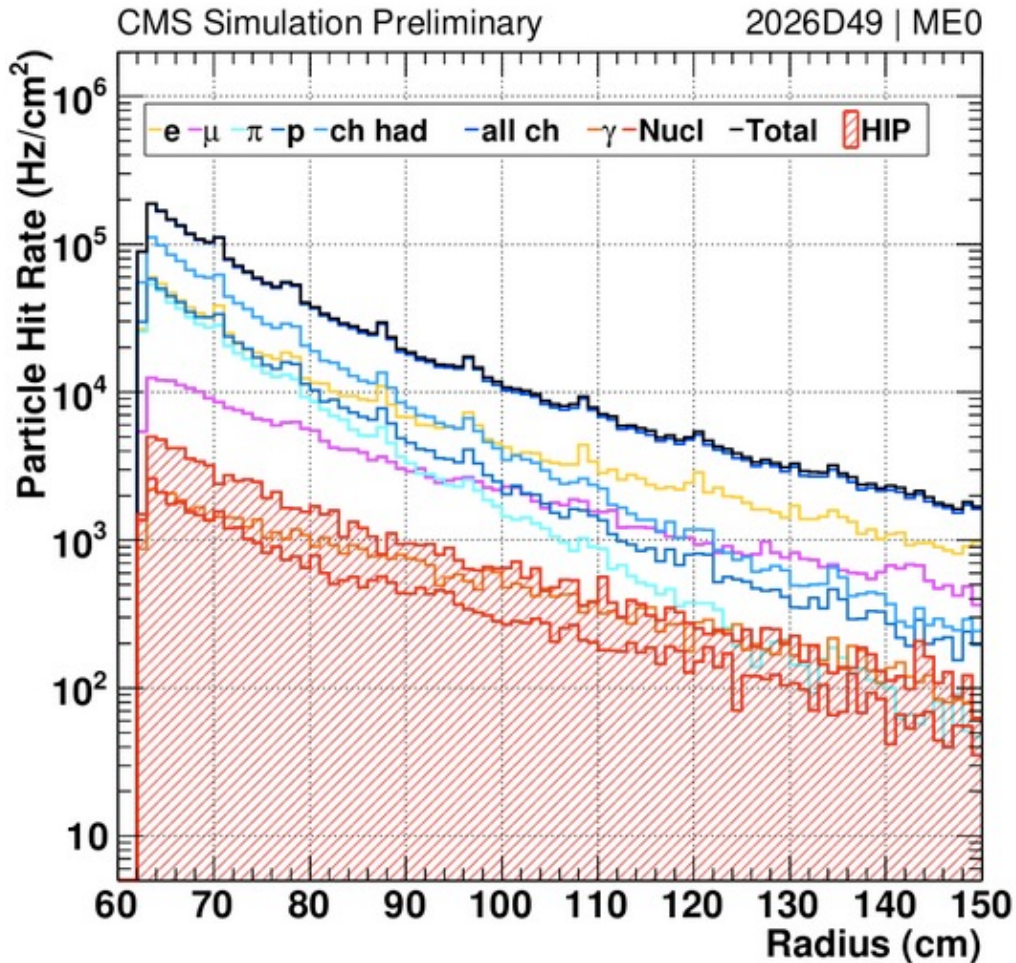
ME0 station behind the new endcap calorimeter HGCAL



- Complementing GEM/CSC for muon p_T measurement in $2 < |\eta| < 2.4$
- Extending CMS Muon System acceptance up to $|\eta| < 2.8$
- 18 ME0 stack per endcap, each made of six layers of triple-GEM detector for efficient tagging of muon tracks
- Each stack covers $\delta\phi = 20^\circ$, $\delta\eta = 0.8$
- **Will face harsh radiation and background conditions**

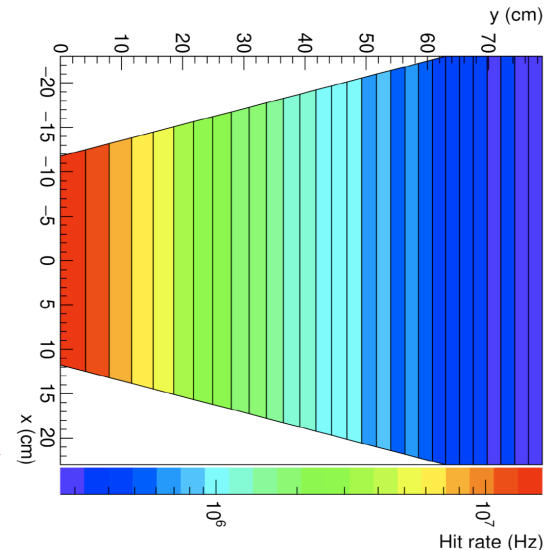


ME0 Background



Expected background in ME0 for the HL-LHC scenario (5×10^{34} Hz/cm²):

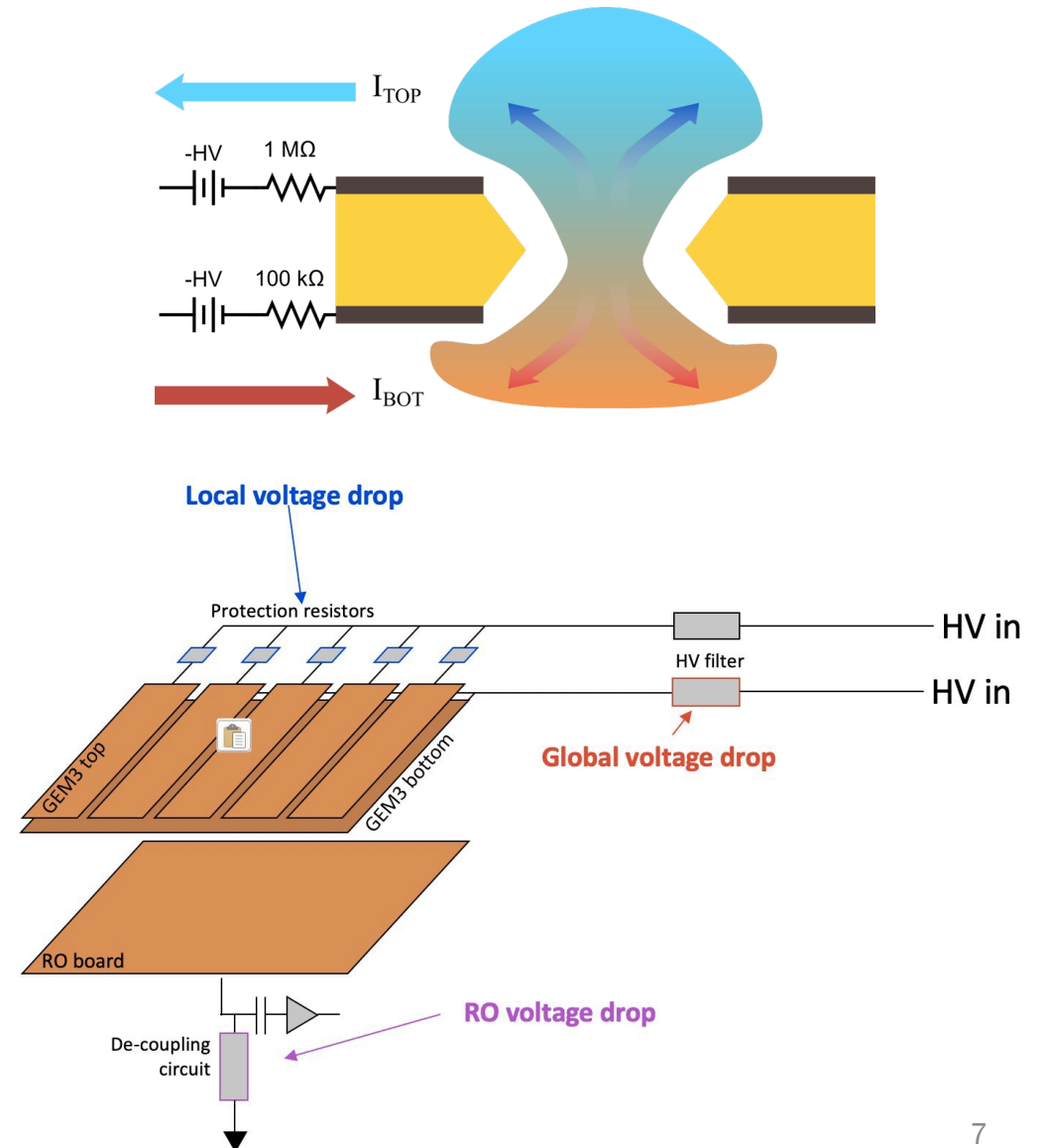
- Rates up to 200 kHz/cm² in the highest- η region
 - Highest of any large-area gaseous detector station in a HEP experiment
 - Corresponding to 150 kHz/cm² average rate in the highest- η readout sector
- Dominated by charged hadrons
- Highly uneven background as a function of distance from beam line



Highly non-uniform rate along the chamber profile

Rate capability of GEM detectors

- **GEM rate capability:**
 - **ion space-charge effects**
 - intrinsic to the GEM technology
 - can be probed by irradiating small areas
 - rate capability of $\mathcal{O}(10^8 \text{ Hz/cm}^2)$
 - not a limiting factor
 - **voltage drop** on the protection and filter resistors
 - depends on the integrate **particle flux per GEM foil sector**
 - rate capability of $\mathcal{O}(10^5 \text{ Hz/cm}^2)$
 - can be tuned by changing the HV design parameters
- Rate capability of the **detector+RO chain:**
 - **dead time** of the electronics, depends on the **signal rate per strip**



Rate capability of GEM detectors

- **GEM rate capability:**

- **ion space-charge effects**

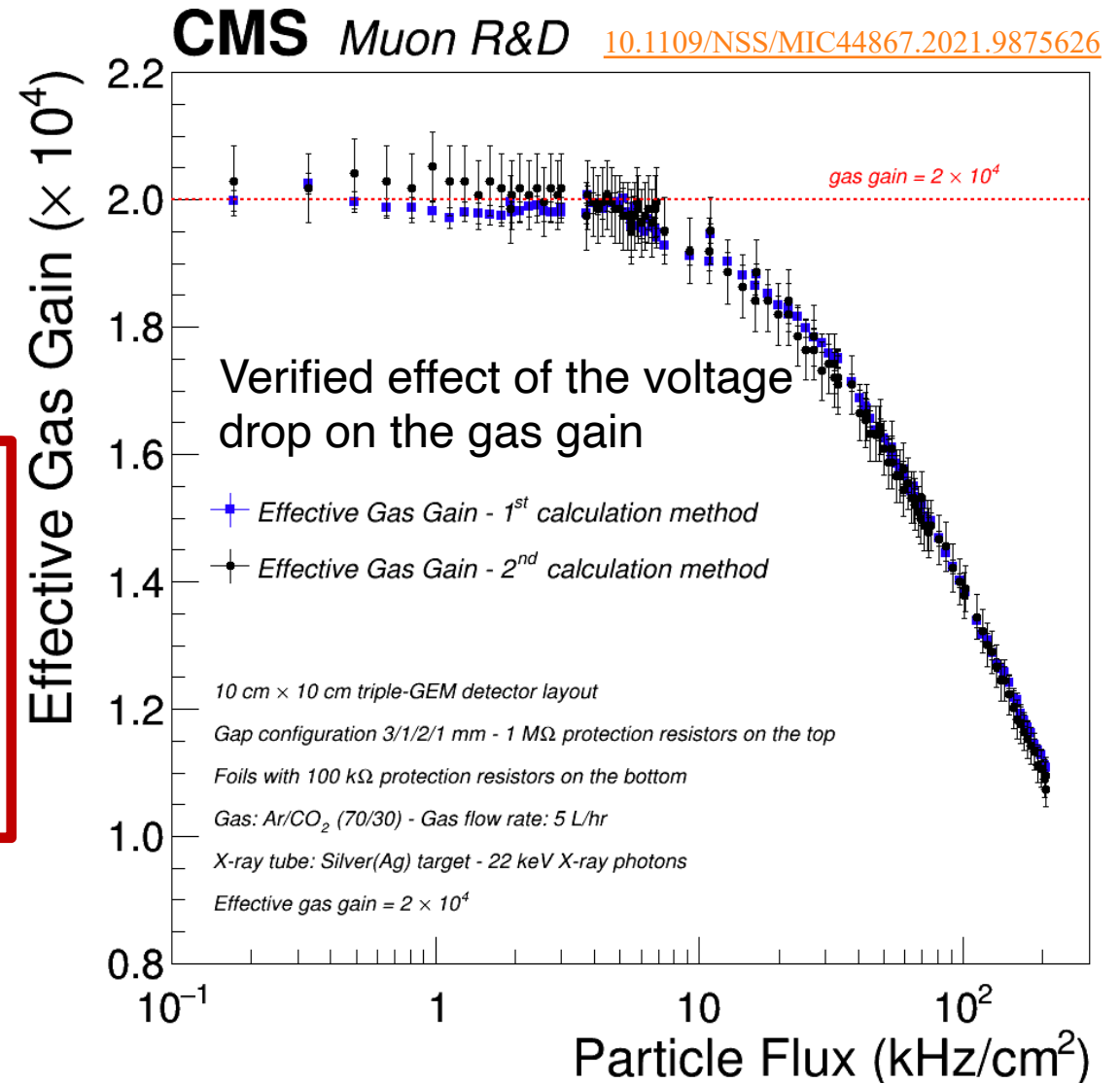
- intrinsic to the GEM technology
- can be probed by irradiating small areas
- rate capability of $\mathcal{O}(10^8 \text{ Hz/cm}^2)$
- not a limiting factor

- **voltage drop** on the protection and filter resistors

- depends on the integrate **particle flux per GEM foil sector**
- rate capability of $\mathcal{O}(10^4 \text{ Hz/cm}^2)$
- can be tuned by changing the HV design parameters

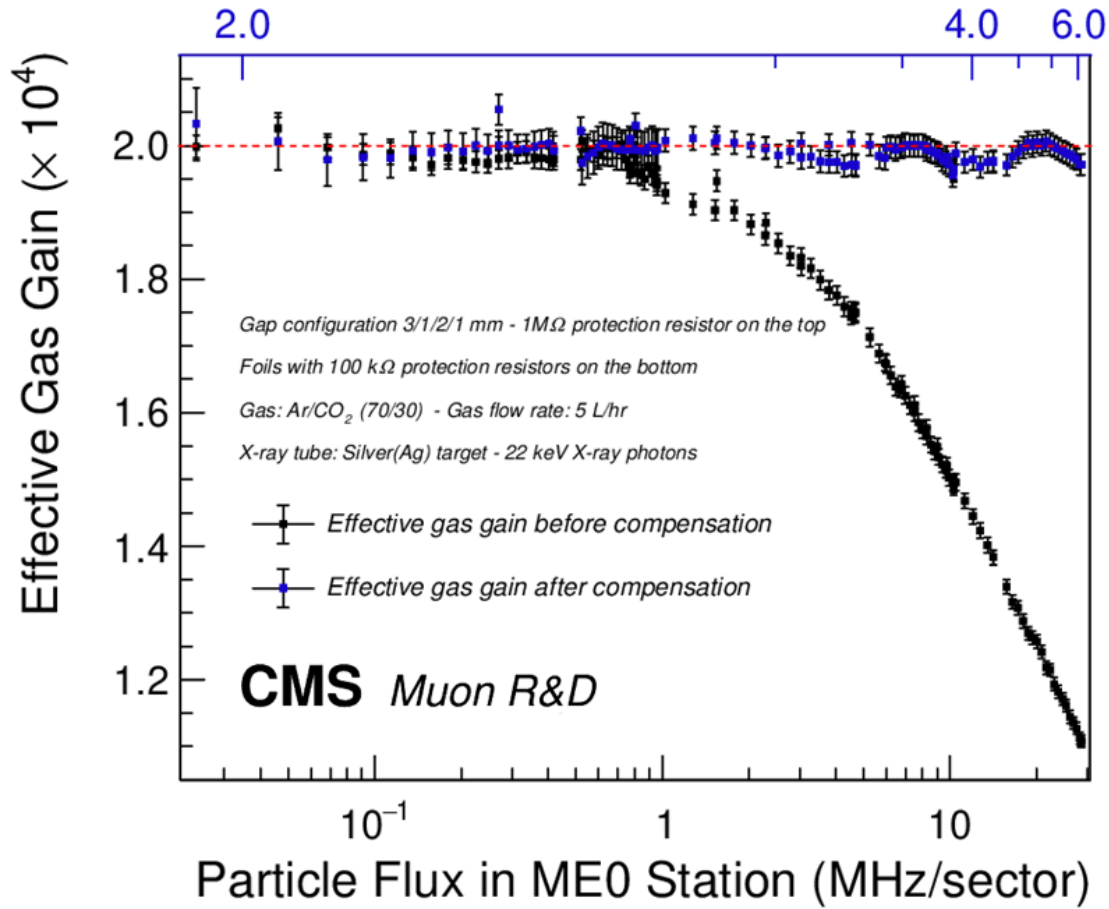
- Rate capability of the **detector+RO chain:**

- **dead time** of the electronics, depends on the **signal rate** per strip



Voltage compensation method

Nominal Operation Gain ($\times 10^4$)



Voltage drop depending on the particle flux, number of primary electron-ion ionisation pairs and protection resistance:

$$V_{eff} = V_{set} - \underbrace{R_{electode}}_{\text{Global electrode resistance}} \times \underbrace{\varphi}_{\text{Flux on the electrode}} \times \underbrace{G}_{\text{Effective gain}} \times \underbrace{n_0}_{\text{Number of primaries}}$$

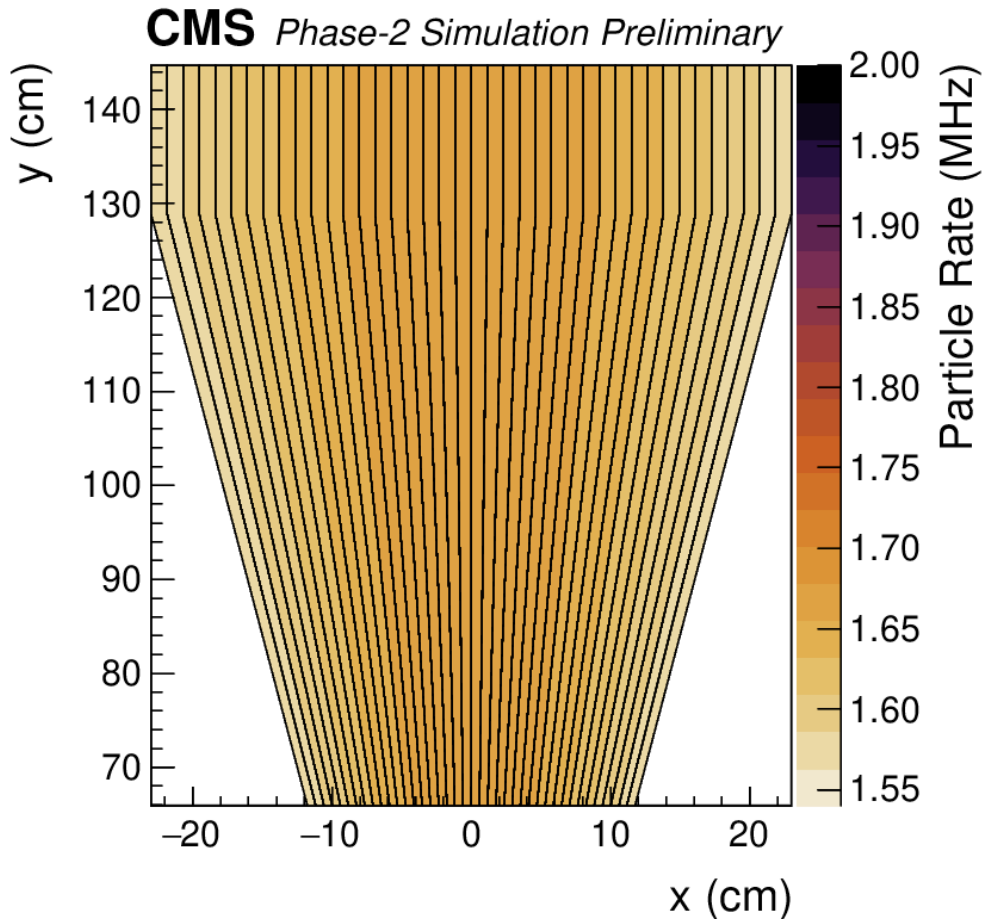
1 – 10V in the ME0 BKG range

Compensation:

- determine iteratively the effective voltage to operate at the nominal gain
- procedure successfully applied to triple-GEM prototypes under x-ray irradiation

In ME0: large voltage drop in the highest ME0 eta sector (10MHz expected rate)

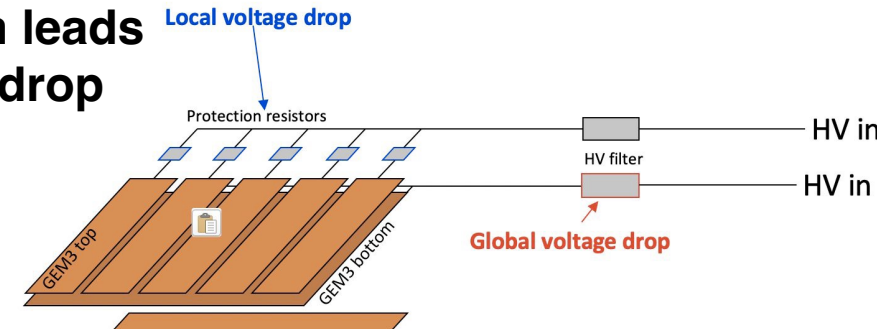
ME0 GEM foil segmentation



- non-uniform background as a function of η
- need to power all HV sectors with a single HV channel

→ standard segmentation leads to highly even voltage drop

→ not possible to apply compensation method



Solution: radial GEM foil segmentation w.r. to beam line

→ Expected equal background particle rate per sector

→ Uniform gain drop per HV sector (at 140PU we expect 1.6 MHz/sect)

ME0 segmentation design:

- 40 sectors
- sector smaller than 100 cm^2 to reduce discharge energy
- cons: dead area at sector separation



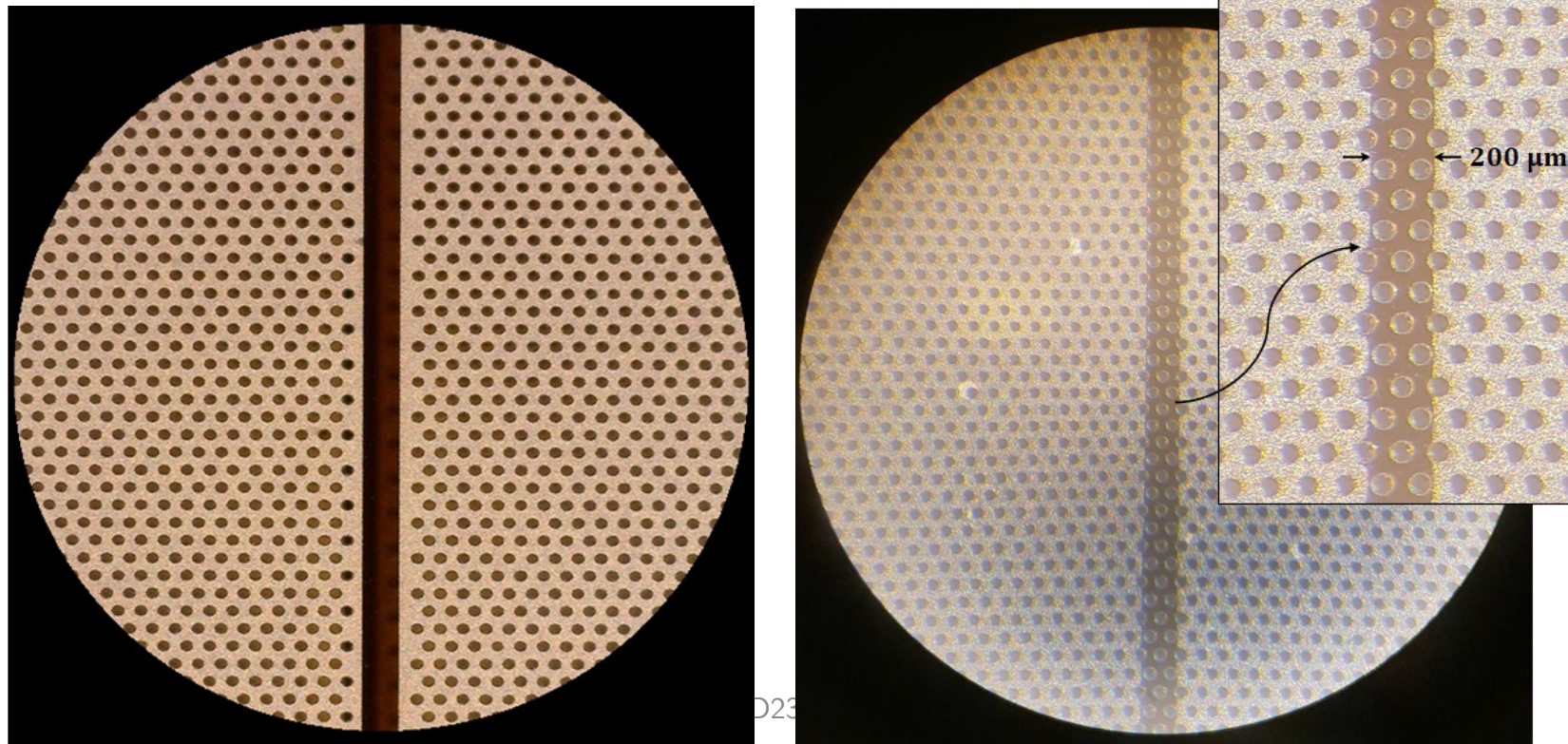
Separation between GEM foil sectors on ME0 detector seen at microscope

ME0 GEM foil segmentation (2)

Radial segmentation leads to **wide dead area (500 μm)**

New technique developed @ CERN MPT workshop: *“Random hole”*

- GEM foil perforated everywhere
- Subsequent removal of 200 μm Cu strip



Validation of the ME0 design

- Validation of the voltage compensation method using radially segmented foils
- Optimization of the HV resistive circuit
- Validation of the radial segmentation design in terms of efficiency
 - comparison between *standard* and *random hole* techniques

X-ray irradiation:

- pro: controlled environment, tunable rate
- cons: only probes local effects (i.e. protection resistors)

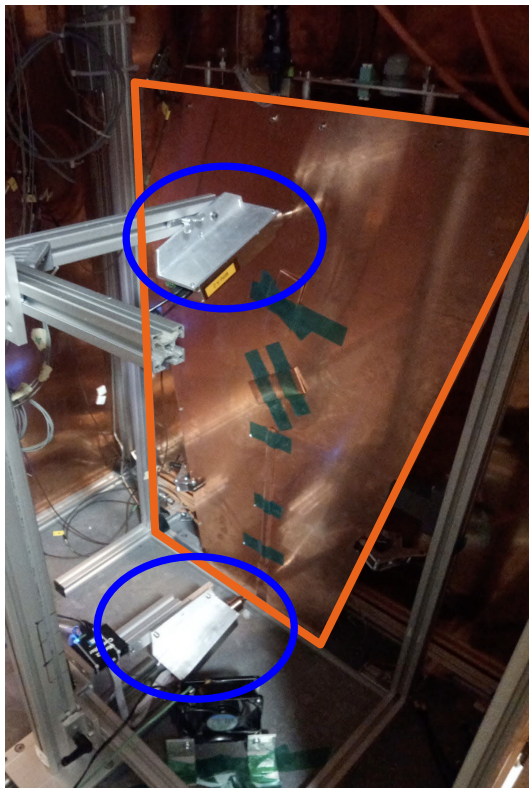
Test beam @ GIF++:

- uniform irradiation, we probe global effects (i.e. HV filter)
- efficiency measurement using reference detector

ME0 rate capability studies with x-rays

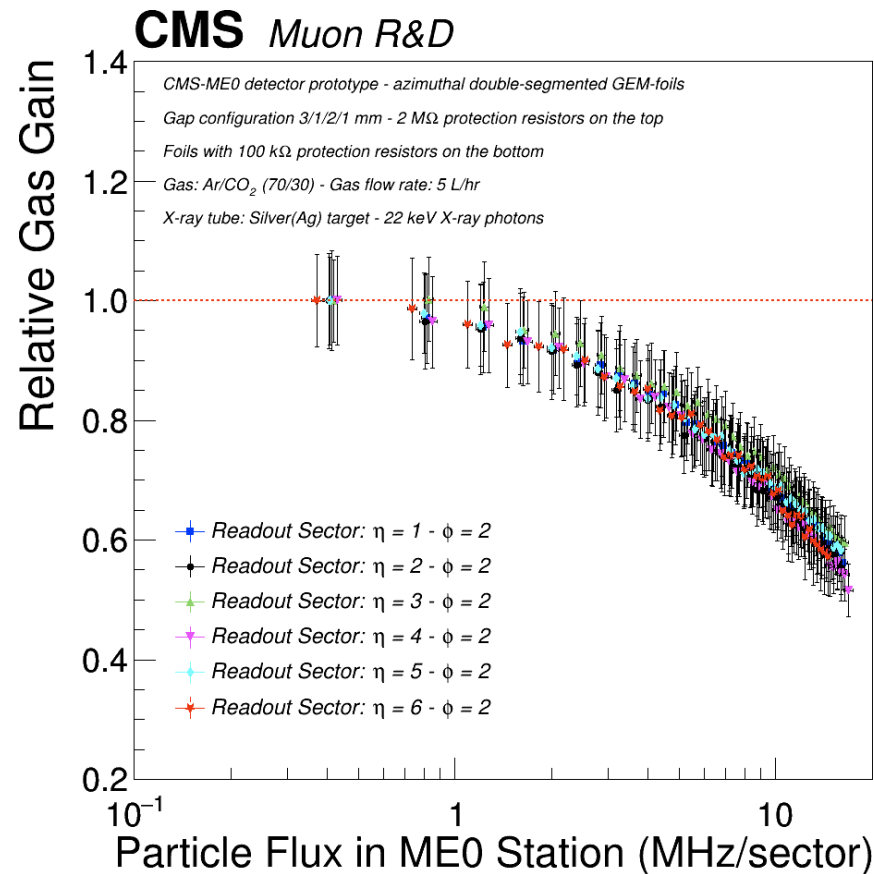
Setup: ME0 layer irradiated using two x-ray guns

- global x-ray irradiation
- high flux on highest η partition of ME0



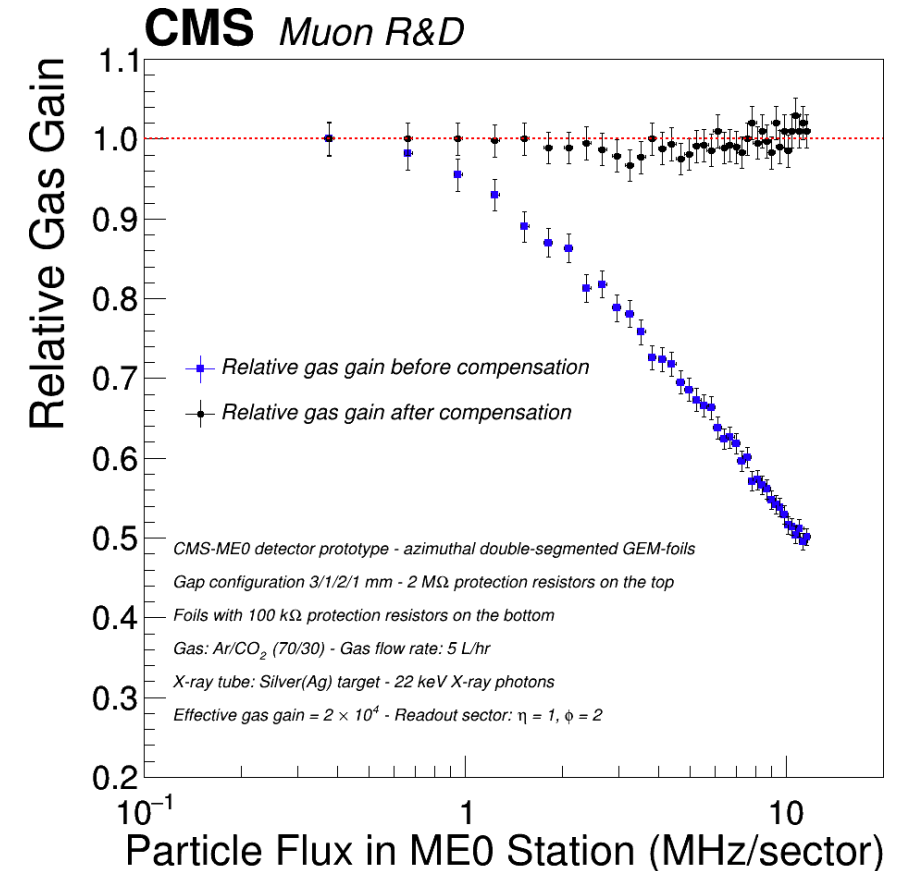
Validation of the radial segmentation design

Gain drop uniform across the sectors



Voltage drop compensation applied to ME0 detector

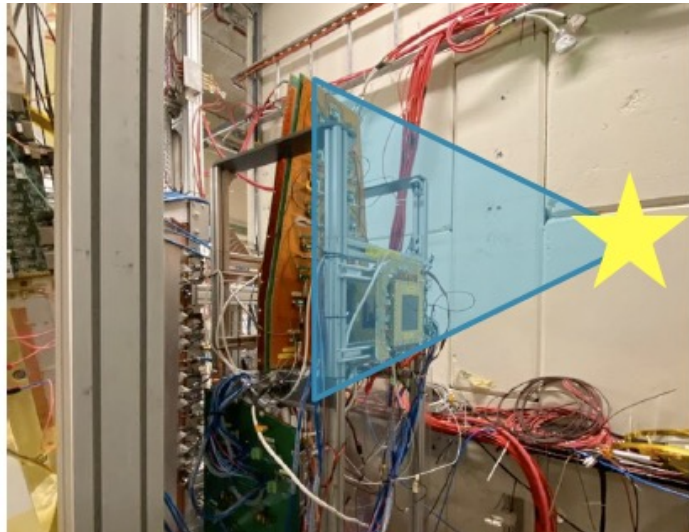
Demonstrated up to 10MHz/sector



ME0 rate capability studies at the GIF++

Setup: ME0 layer + reference GEM tracker

- Placed inside the source cone for uniform and intense irradiation
- Full RO chain (VFAT3 frontend)

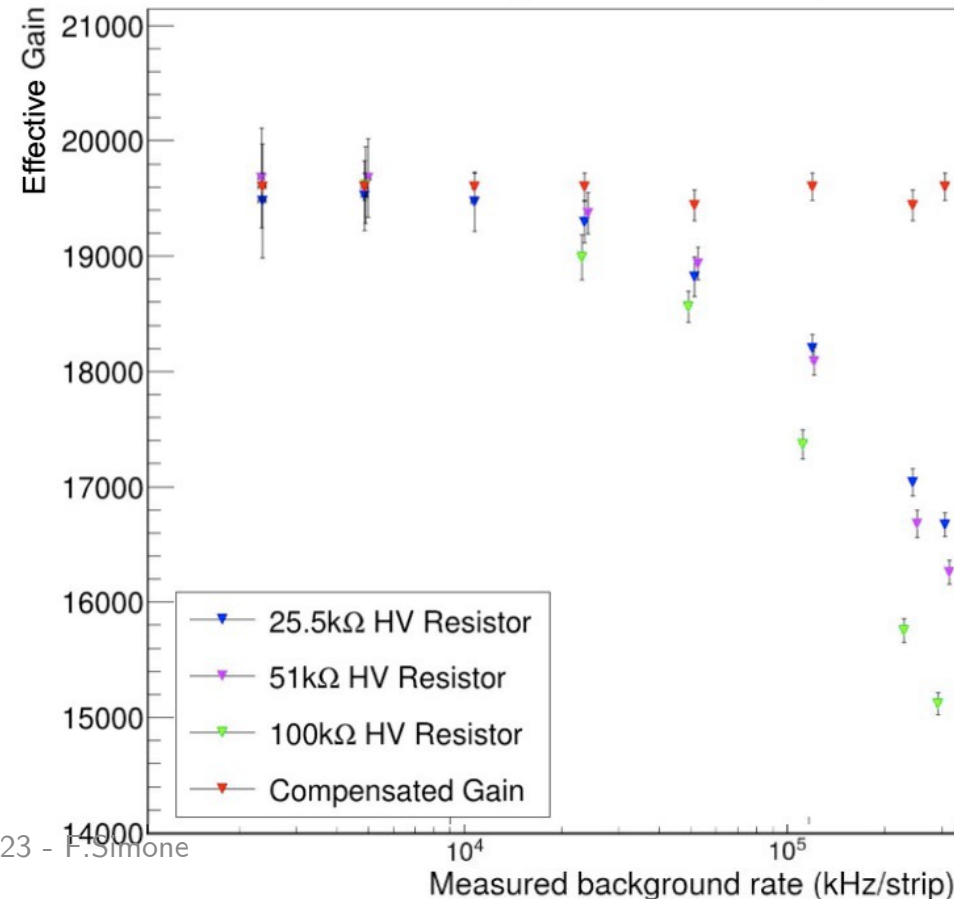


Source:
 ^{137}Cs (14TBq)
 γ (662 keV)

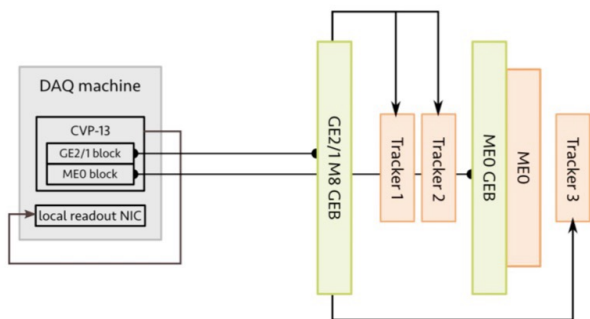
Compensation demonstrated with different HV filters

Gain recovery demonstrated up to 2.2 MHz/sector or 280 kHz/strip and with different HV filters up to 100 k Ω

CMS Muon Preliminary ME0 detector @ GIF++



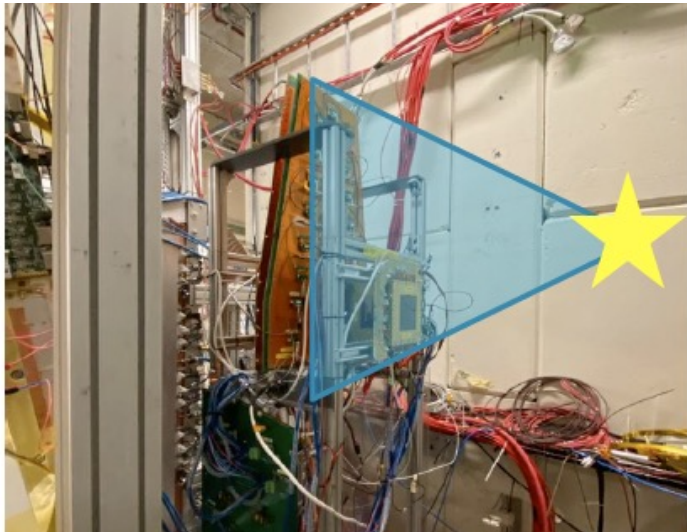
back-end area experimental area (GIF++ bunker)



ME0 efficiency at the GIF++

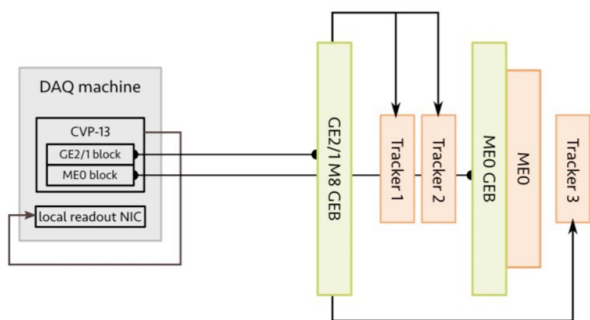
Background:

137 Cs (14TBq) γ (662 keV)
+ SPS beam of 80 GeV muons



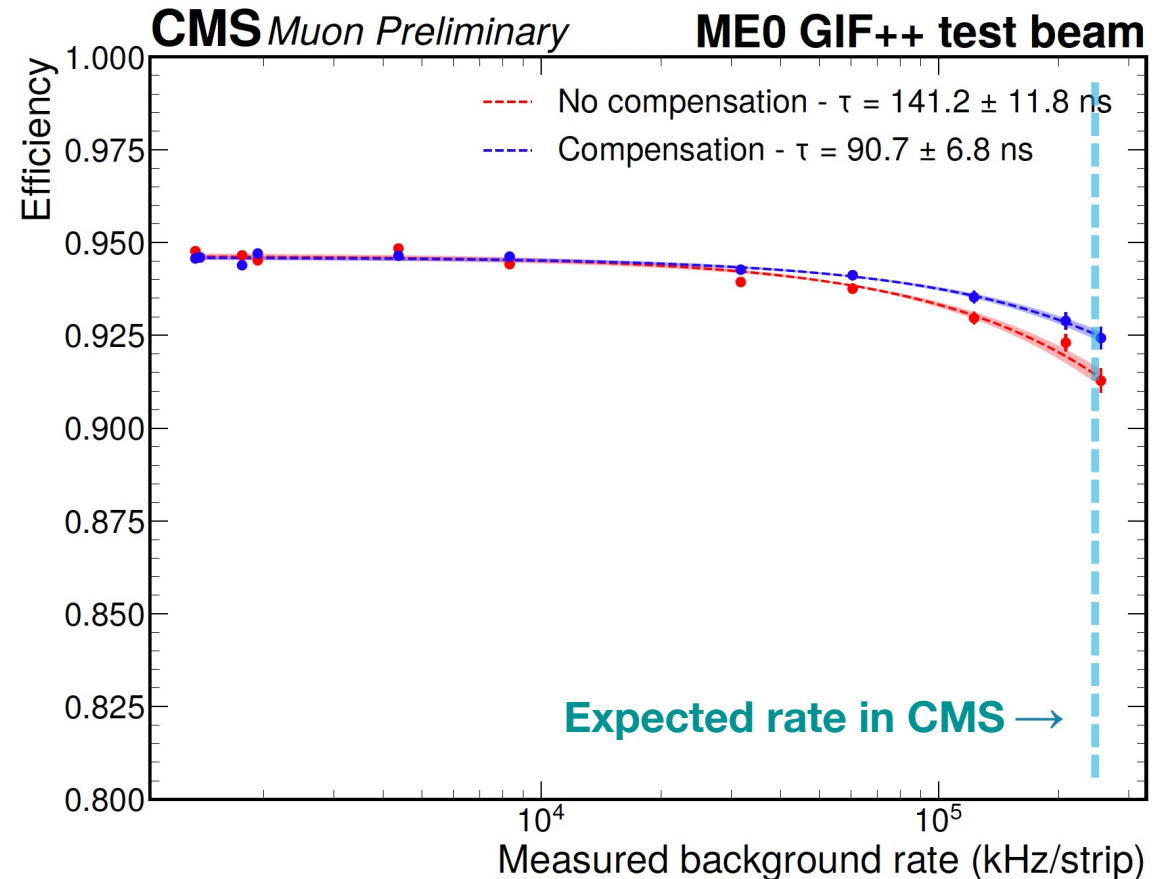
back-end area

experimental area (GIF++ bunker)



Validation of detector + RO electronics

- Efficiency loss not recovered by voltage compensation.
 - Due to frontend chip dead time (400 ns)
 - Limited impact (3%) at CMS expected rate.



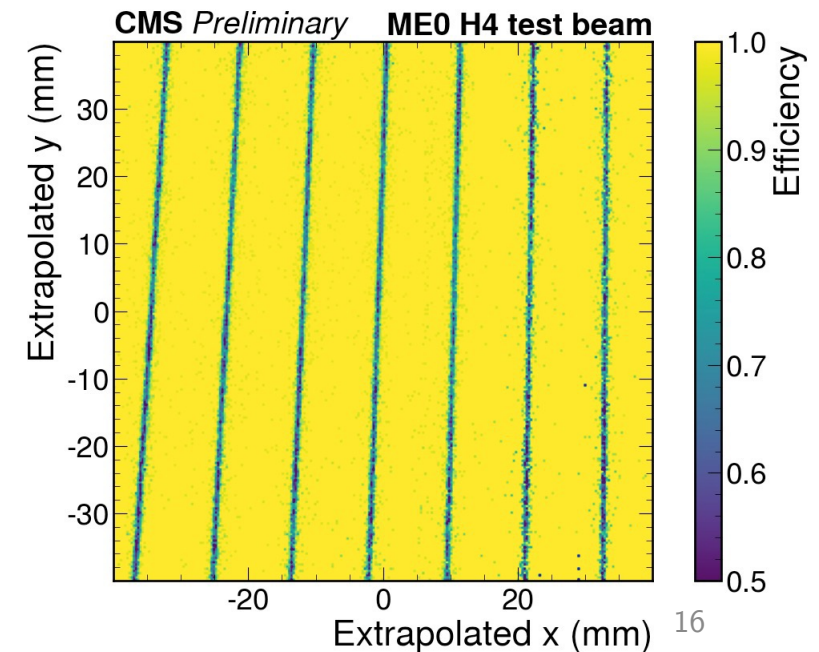
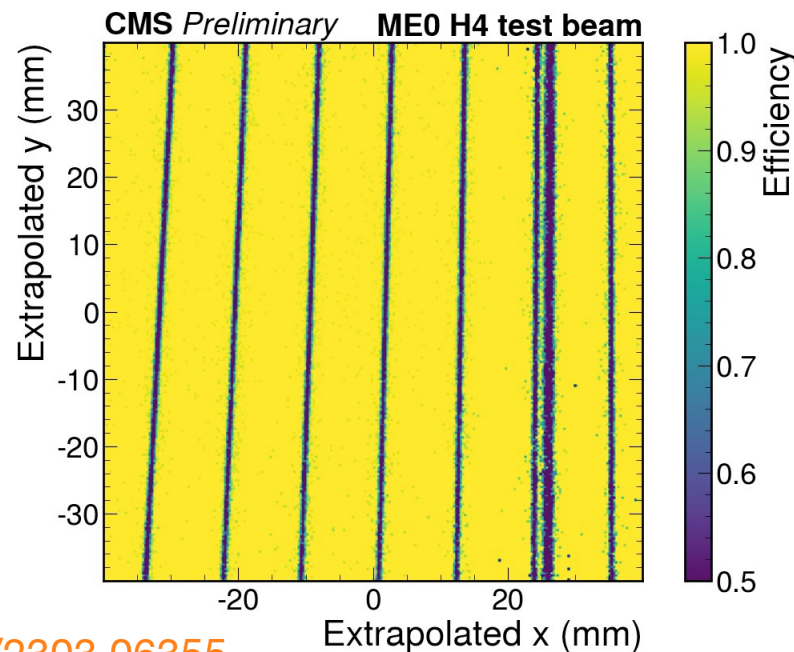
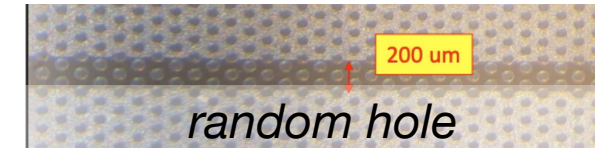
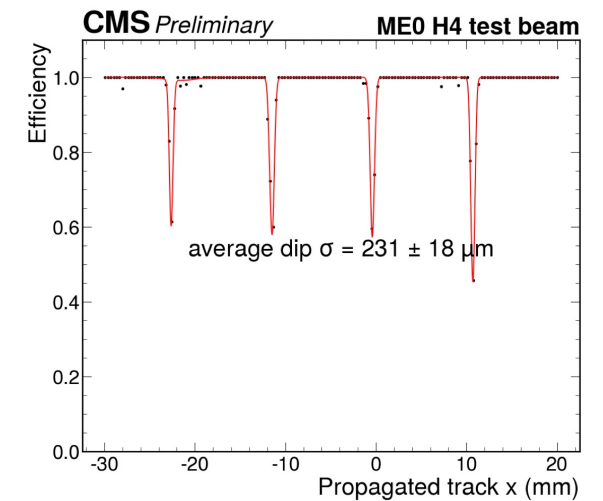
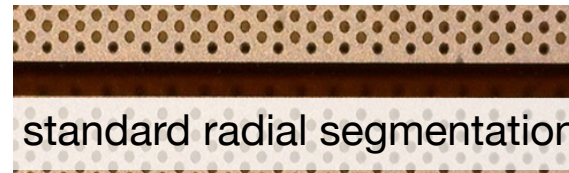
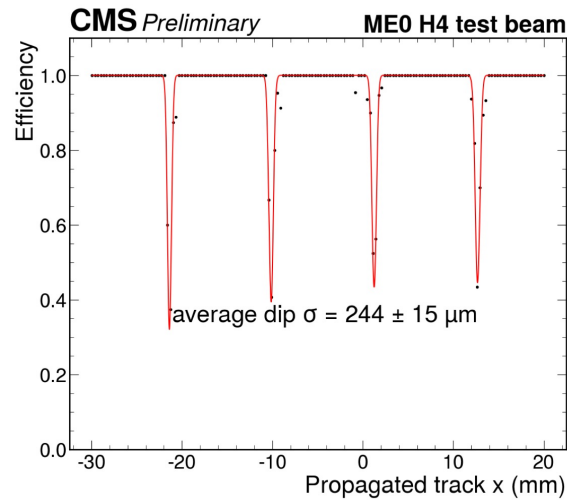
ME0 efficiency studies

Performance studies under pion and muon irradiation at SPS H4

- **Spatial resolution** of $240 \mu\text{rad}$
- Local efficiency $>99\%$
- **Loss of efficiency** due to dead area at **HV sectorisation**
- **Recovered** adopting **random hole segmentation**

Random hole is still in R&D phase, not in the final design despite the promising results due to time constraints.

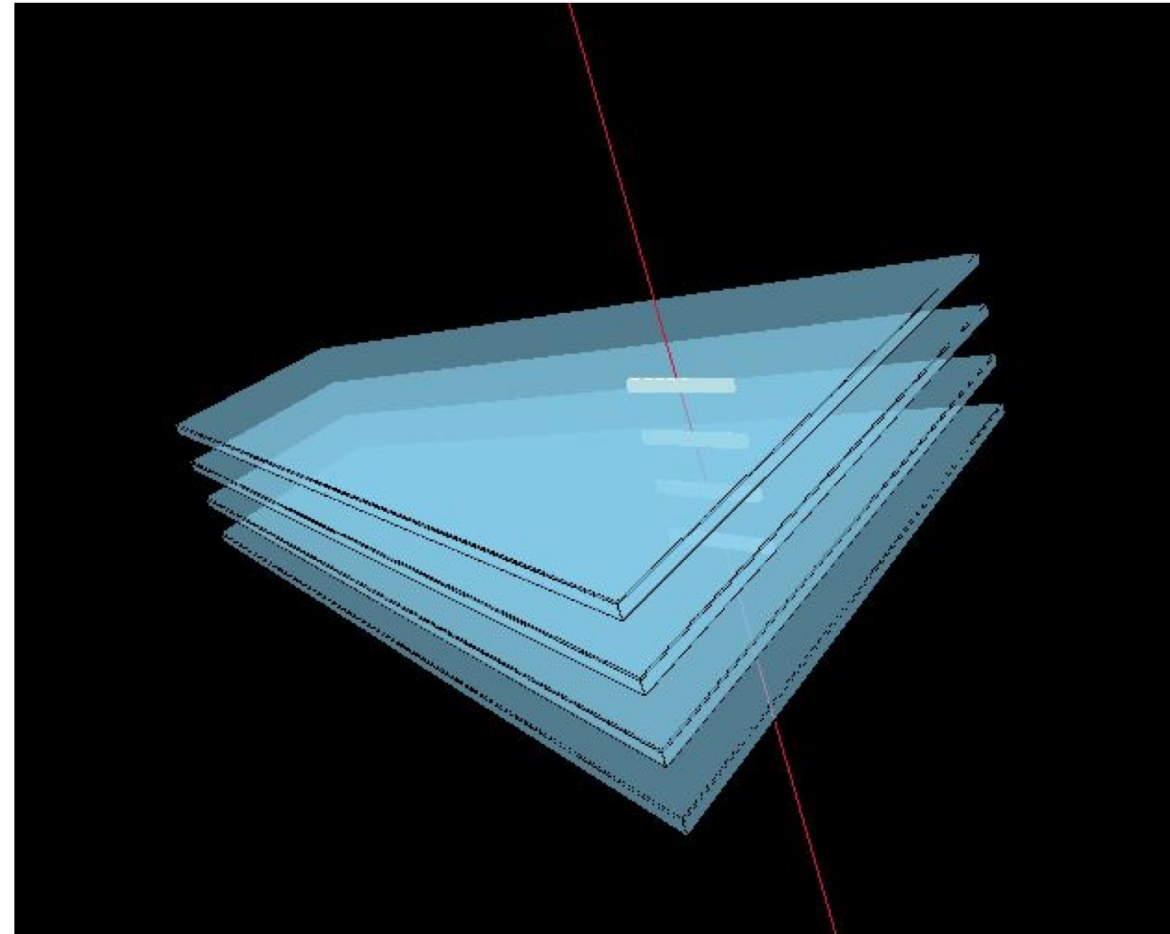
<https://arxiv.org/abs/2303.06355>



Conclusions and perspectives

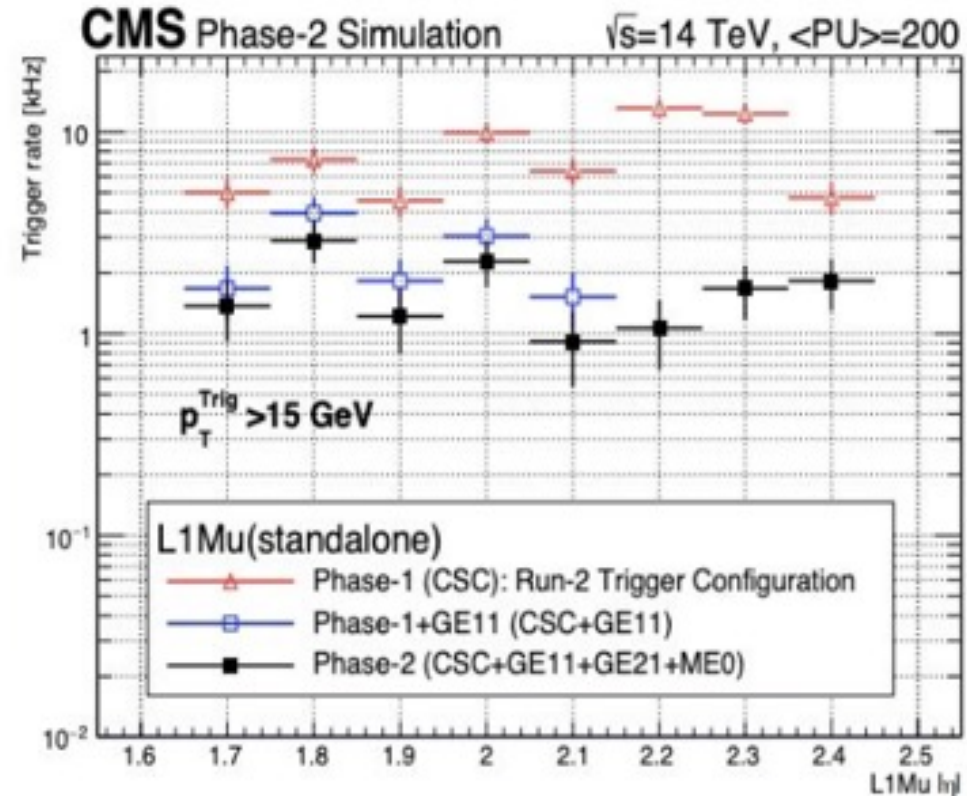
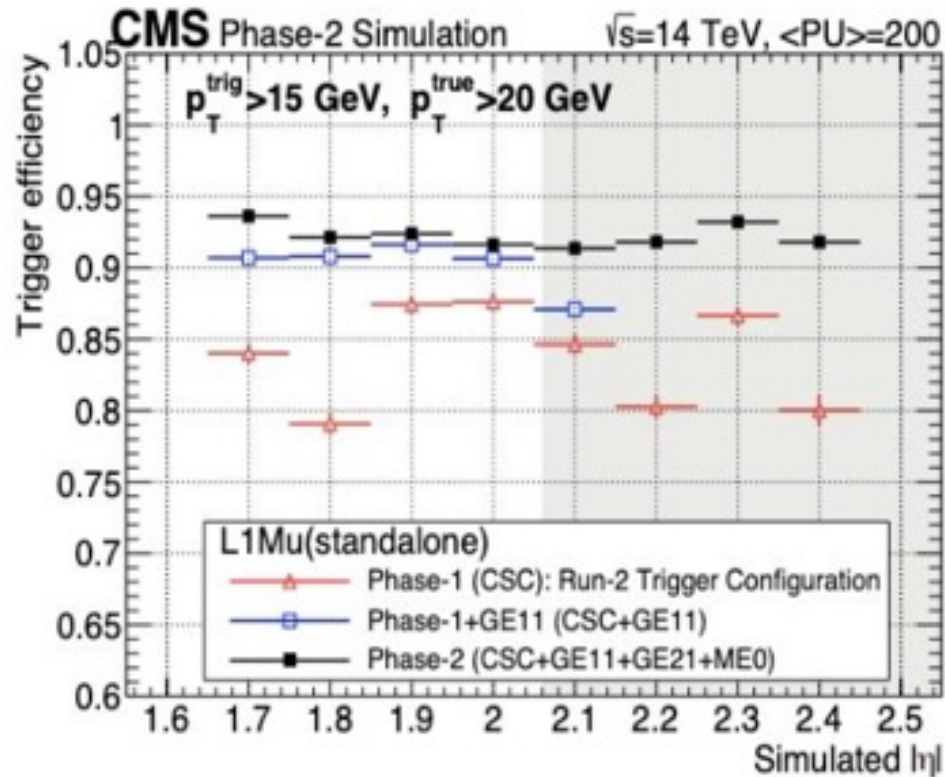
ME0 R&D on the detector design at very advanced stage

- Accessed rate capability
- Implemented mitigation strategies: radial HV segmentation, voltage drop compensation
- Quantified impact of HV filters
- Design validated and fixed
- Started pre-production
 - ME0 foils mass-production is going to start (Sept 2023)
 - Installation in January 2027

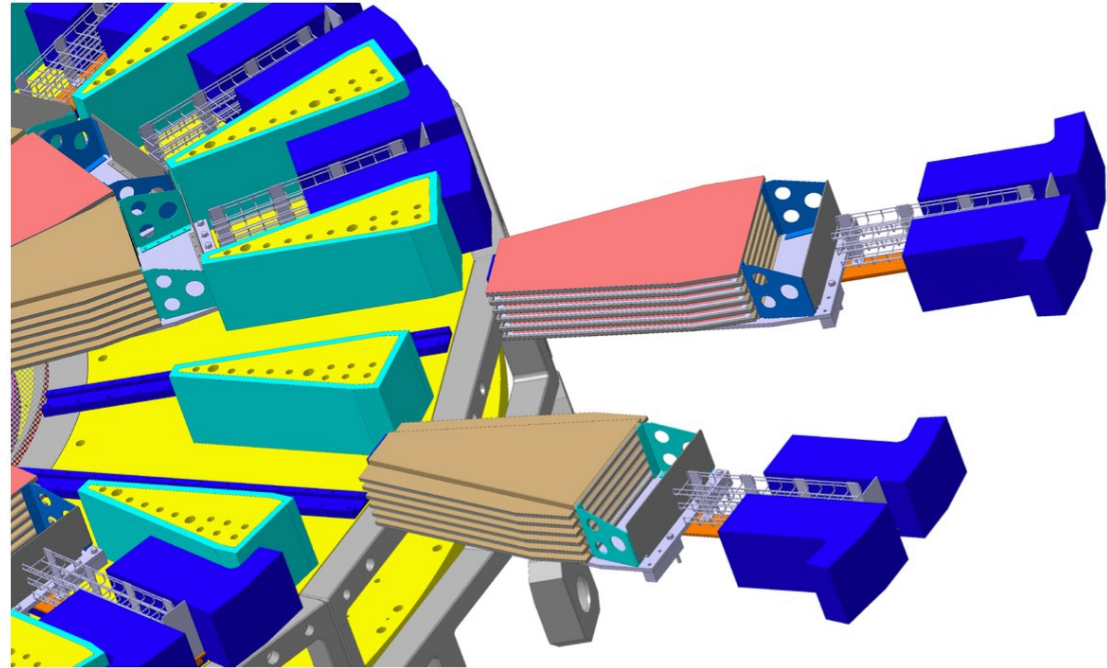


Backup

GEM upgrade: motivations



LHC schedule



LHC

HL-LHC



ME0 Installation



MEO ELECTRONICS

VFAT3: 128-channel front-end ASIC for digital readout

- Common plugin-card format for GE2/1 and MEO
- Ongoing final checks on channel input protection circuit (see later)

GEM Electronic Board (GEB): 1 mm 8-layer PCB providing electrical links, powering the front-end and shielding the detector

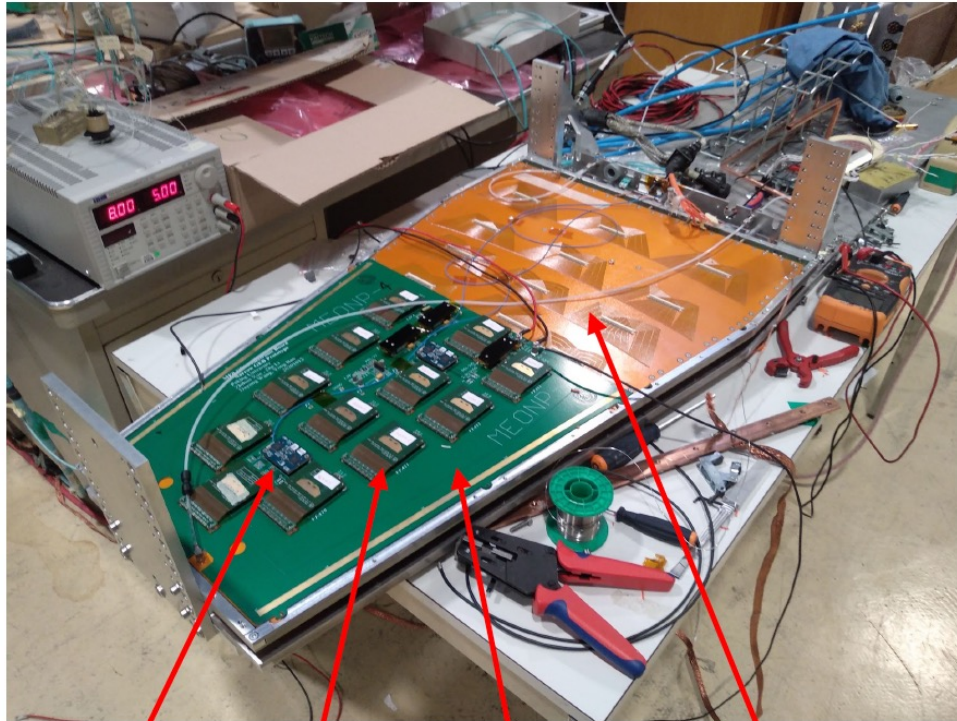
DC-DC converter: FEASTs to be replaced by bPOLs

OptoHybrid: Front-end concentrator, reads out 6 VFATs

- 2 lpGBT (main/secondary) for front-end, 1 VTRx+ to back-end
- No FPGA, radiation-hard electronics

X2O ATCA board: common back-end for CSC, GE2/1 and MEO

All front-end components in pre-production state and operated extensively in lab & test beam



OptoHybrid

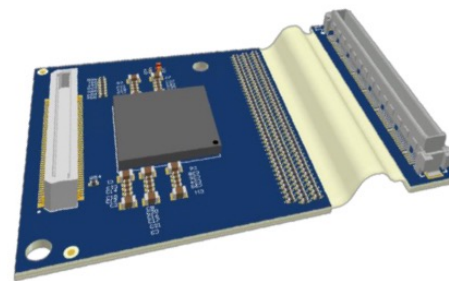
VFAT3

GEB

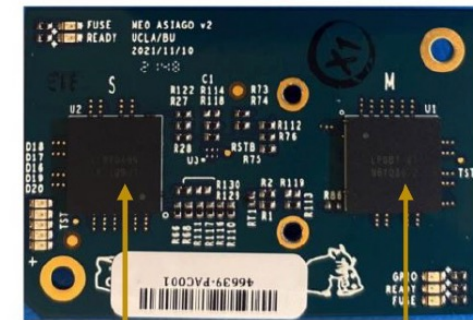
R/O board



bPOL ASIC on FEAST module



VFAT3 plug-in card



OptoHybrid

Secondary (S)
lpGBT

Main (M)
lpGBT